



Amendments to the Claims:

This listing of the claims will replace all prior versions, and listings of claims in the application.

Listings of Claims:

Please cancel Claims 31 - 33, and 36 - 38.

1. (Previously Presented) A magnetic detecting element comprising:
a multilayer film comprising a laminate of a free magnetic layer, a nonmagnetic material layer, a pinned magnetic layer and an antiferromagnetic layer; wherein a current flows perpendicularly to a film plane of each of the layers of the multilayer film, and the free magnetic layer comprises a plurality of magnetic layers which are laminated through a current limiting layer containing an insulating portion and a conductive portion.

2. (Previously Presented) A magnetic detecting element comprising:
a multilayer film comprising an upper nonmagnetic material layer, an upper pinned magnetic layer and an upper antiferromagnetic layer, which are laminated above a free magnetic layer, and a lower nonmagnetic material layer, a lower pinned magnetic layer and a lower antiferromagnetic layer, which are laminated below the free magnetic layer;
wherein a current flows perpendicularly to a film plane of each of the layers of the multilayer film, and the free magnetic layer comprises a plurality of magnetic layers which are laminated through a current limiting layer containing an insulating portion and a conductive portion.

3. (Previously Presented) A magnetic detecting element according to claim 1 or 2, further comprising hard bias layers formed on both sides of the free magnetic layer in a track width direction, for aligning magnetization of the free magnetic layer.

4. (Previously Presented) A magnetic detecting element according to claim 1 , further comprising an in-stack bias layer laminated at least one of above and below the free magnetic layer, for aligning magnetization of the free magnetic layer.

5. (Original) A magnetic detecting element according to claim 1, wherein magnetizations of the plurality of magnetic layers 10 are parallel to each other.

6. (Original) A magnetic detecting element according to claim 5, wherein the plurality of magnetic layers are ferromagnetically coupled with each other through the current 15 limiting layer.

7. (Original) A magnetic detecting element according to claim 1, wherein magnetizations of the plurality of the magnetic layers are antiparallel to each other.

8. (Original) A magnetic detecting element according to claim 1, wherein the plurality of the magnetic layers constituting the free magnetic layer have a same magnetic moment per unit area.

9. (Original) A magnetic detecting element according to claim 1, wherein the plurality of the magnetic layers constituting the free magnetic layer have different magnetic moments per unit area.

10. (Original) A magnetic detecting element according to claim 1, wherein the plurality of the magnetic layers constituting the free magnetic layer have a same thickness.

11. (Original) A magnetic detecting element according to claim 1, wherein the plurality of the magnetic layers constituting the free magnetic layer have different thicknesses.

12. (Original) A magnetic detecting element according to claim 7, wherein the free magnetic layer comprises a nonmagnetic intermediate layer composed of at least one nonmagnetic material of Ru, Rh, Ir, Os, Re, Cr, and Cu.

13. (Previously Presented) A magnetic detecting element comprising:
a multilayer film comprising a laminate of a free magnetic layer, a nonmagnetic material layer, a pinned magnetic layer and an antiferromagnetic layer;
wherein a current flows perpendicularly to a film plane of each of the layers of the multilayer film, and a current limiting layer containing an insulating portion and a conductive portion is interposed between the free magnetic layer and the nonmagnetic material layer.

14. (Previously Presented) A magnetic detecting element comprising:
a multilayer film comprising an upper nonmagnetic material layer, an upper pinned magnetic layer and an upper antiferromagnetic layer, which are laminated above a free magnetic layer, and a lower nonmagnetic material layer, a lower pinned magnetic layer and a lower antiferromagnetic layer, which are laminated below the free magnetic layer;
wherein a current flows perpendicularly to a film plane of each of the layers of the multilayer film, and a current limiting layer containing an insulating portion and a conductive portion is interposed between the free magnetic layer and one of the nonmagnetic material layers.

15. (Previously Presented) A magnetic detecting element according to claim 13, further comprising a noble metal material layer formed at at least one or both of the top and bottom of the current limiting layer.

16. (Original) A magnetic detecting element according to claim 15, wherein the noble metal material layer comprises at least one noble metal material of Ru, Pt, Au, Rh, Ir, Pd, Os and Re.

17. (Original) A magnetic detecting element according to claim 15, wherein a Cu layer is formed instead of the noble metal material layer.

18. (Previously Presented) A magnetic detecting element according to claim 13, wherein the insulating portion of the current limiting layer comprises an insulating material film having a plurality of holes extending from a top to a bottom of the current limiting layer, the holes being filled with a conductive material film serving as the conductive portion.

19. (Previously Presented) A magnetic detecting element according to claim 13, wherein the insulating portion of the current limiting layer comprises an insulating material film having a groove continuously extending in a plan view parallel to the film plane and extending from a top to a bottom of the current limiting layer, the groove being filled with a conductive material film serving as the conductive portion.

20. (Previously Presented) A magnetic detecting element according to claim 13, wherein the insulating portion of the current limiting layer comprises an insulating material film containing a hole extending from a top to a bottom of the current limiting layer and a groove which continuously extends in a plan view parallel to the film plane and extends from the top to the bottom of the current limiting layer, the hole and groove being filled with a conductive material film serving as the conductive portion.

21. (Previously Presented) A magnetic detecting element according to claim 20, wherein the insulating material film comprises one of an oxide film and nitride film.

22. (Original) A magnetic detecting element according to claim 13, wherein the conductive portion of the current limiting layer comprises conductive particles which are dispersed in an insulating material layer serving as the insulating portion.

23. (Withdrawn) A magnetic detecting element according to claim 13, wherein the insulating portion of the current limiting layer comprises insulating particles which are dispersed in a conductive material film serving as the conductive portion.

24. (Original) A method of manufacturing a magnetic detecting element comprising the steps of:

(a) laminating a first electrode layer, an antiferromagnetic layer, a pinned magnetic layer, a nonmagnetic material layer, a first magnetic layer constituting a free magnetic layer, and a current limiting layer containing an insulating portion and a conductive portion in that order from below;

(b) laminating a second magnetic layer constituting the free magnetic layer on the current limiting layer; and

(c) laminating a second electrode layer.

25. (Original) A method of manufacturing a magnetic detecting element according to claim 24, wherein the first and second magnetic layers constituting the free magnetic layer are ferromagnetically coupled with each other through the current limiting layer.

26. (Original) A method of manufacturing a magnetic detecting element according to claim 24, wherein the first and second magnetic layers constituting the free magnetic layer preferably have a same magnetic moment per unit area.

27. (Original) A method of manufacturing a magnetic detecting element according to claim 24, wherein the first and second magnetic layers constituting the free magnetic layer have different magnetic moments per unit area.

28. (Original) A method of manufacturing a magnetic detecting element according to claim 24, wherein the first and second magnetic layers constituting the free magnetic layer preferably have a same thickness.

29. (Original) A method of manufacturing a magnetic detecting element according to claim 24, wherein the first and second magnetic layers constituting the free magnetic layer have different thicknesses.

30. (Original) A method of manufacturing a magnetic detecting element according to claim 24, further comprising, between the steps (b) and (c), (d) a step of laminating a nonmagnetic material layer, a pinned magnetic layer and an antiferromagnetic layer on the free magnetic layer.

Claims 31- 33 are cancelled.

34. (Original) A method of manufacturing a magnetic detecting element comprising the steps of:

- (e) laminating a first electrode layer, an antiferromagnetic layer, a pinned magnetic layer, a nonmagnetic material layer, and a current limiting layer containing an insulating portion and a conductive portion in that order from below;
- (f) laminating a free magnetic layer on the current limiting layer; and
- (g) laminating a second electrode layer.

35. (Original) A method of manufacturing a magnetic detecting element according to claim 34, further comprising, between the steps (f) and (g), (h) a step of laminating a nonmagnetic material layer, a pinned magnetic layer and an antiferromagnetic layer on the free magnetic layer.

Claims 36 – 38 are cancelled.

39. (Previously Presented) A method of manufacturing a magnetic detecting element according to claim 34, wherein one of a noble metal material layer composed of a noble metal element and a Cu layer composed of Cu is formed on one of the first magnetic layer and the free magnetic layer in the step (a), and then the current limiting layer is formed on the one of the noble metal material layer or the Cu layer.

40. (Previously Presented) A method of manufacturing a magnetic detecting element according to claim 34, wherein one of a noble metal material layer composed of a noble metal element and a Cu layer composed of Cu is formed on the current limiting layer after the current limiting layer is formed.

41. (Original) A method of manufacturing a magnetic detecting element according to claim 40, wherein the noble metal material is at least one of Ru, Pt, Au, Rh, Ir, Pd, Os, and Re.

42. (Previously Presented) A magnetic detecting element according to claim 2, further comprising an in-stack bias layer laminated at least one of above and below the free magnetic layer, for aligning magnetization of the free magnetic layer.